

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re U.S. Patent Application of:  
Tayanaka

Serial No.: 10/067,486

Filed: February 4, 2002

For: **SEMICONDUCTOR SUBSTRATE  
AND THIN FILM SEMICONDUCTIVE  
MEMBER, AND METHOD FOR  
MAKING THEREOF**



Examiner: To be determined

Group Art Unit: 2822

**PRELIMINARY AMENDMENT**

Assistant Commissioner for Patents  
Washington, DC 20231

Dear Sir:

Prior to examination on the merit, please amend the above-captioned application as follows:

**In the Specification**

On page 11, please delete the following paragraph:

--FIG. 22 is a schematic cross-sectional view of another porous layer in Example 4 in accordance with the present invention.--

Respectfully submitted,

SONNENSCHN NATH & ROSENTHAL

By: \_\_\_\_\_

Jeffrey F. Craft

Registration No. 30,044

SONNENSCHN NATH & ROSENTHAL  
P.O. Box #061080  
Wacker Drive Station, Sears Tower  
Chicago, IL 60606